## **Excellent Integrated System Limited**

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Fairchild Semiconductor</u> <u>KSA1378YBU</u>

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>





## **KSA1378**

## **Low Frequency Power Amplifier**

- Collector Power Dissipation : P<sub>C</sub>= 300mW
  Complement to KSC3488



## **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	-30	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-25	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current (DC)	-300	mA
I <sub>CP</sub>	* Collector Current (Pulse)	-500	mA
P <sub>C</sub>	Collector Power Dissipation	300	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

<sup>\*</sup> PW≤10ms, Duty cycle≤50%

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

	u					
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{C}$ = -100 $\mu$ A, $I_{E}$ =0	-30			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> =0	-25			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E}$ = -10 $\mu$ A, $I_{C}$ =0	-5			nA
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -25V, I <sub>E</sub> =0			-100	mA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = -3V, I <sub>C</sub> =0			-100	nA
h <sub>FE</sub>	* DC Current Gain	V <sub>CE</sub> = -1V, I <sub>C</sub> = -50mA	70		400	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> = -300mA, I <sub>B</sub> = -30mA		-0.35	-0.6	V

<sup>\*</sup> Pulse Test: PW≤350μs, Duty cycle≤2%

## **h**<sub>FE</sub> Classification

Classification	0	Υ	G
h <sub>FE</sub>	70 ~ 140	120 ~ 240	200 ~ 400

Rev. A1, June 2001 ©2001 Fairchild Semiconductor Corporation



## **Typical Characteristics**

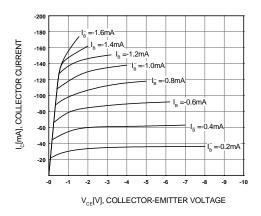


Figure 1. Static Characteristic

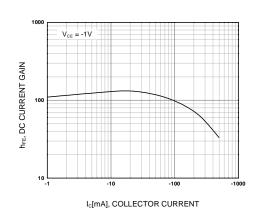


Figure 2. DC current Gain

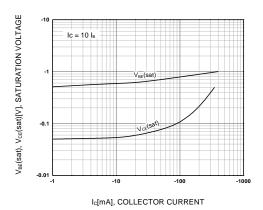


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

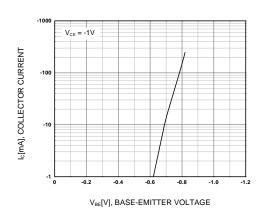


Figure 4. Base-Emitter On Voltage

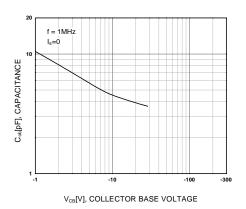


Figure 5. Collector Output Capacitance

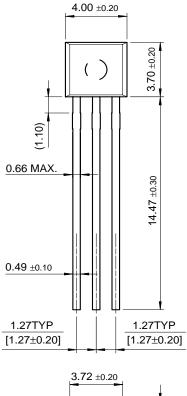
©2001 Fairchild Semiconductor Corporation Rev. A1, June 2001

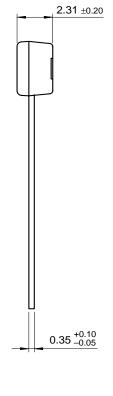
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com





## **TO-92S**





3.72 ±0.20

Dimensions in Millimeters

# Distributor of Fairchild Semiconductor: Excellent Integrated System Limited Datasheet of KSA1378YBU - TRANS PNP 25V 0.3A TO-92S

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

#### **TRADEMARKS**

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

FAST<sup>®</sup> OPTOPLANAR™ STAR\*POWER™ Bottomless™ FASTr™ PACMAN<sup>TM</sup> Stealth™ CoolFET™  $\mathsf{FRFET}^\mathsf{TM}$  $POP^{TM}$ SuperSOT™-3  $CROSSVOLT^{TM}$ GlobalOptoisolator™ Power247™ SuperSOT™-6  $\mathsf{PowerTrench}^{\texttt{®}}$ DenseTrench™ GTO™ SuperSOT™-8 DOME™ HiSeC™ QFET™ SyncFET™ TruTranslation™ EcoSPARK™ ISOPLANAR™ QSTM E<sup>2</sup>CMOS™ LittleFET™ QT Optoelectronics™ TinyLogic™ UHC™ EnSigna™ MicroFET™ Quiet Series™  $\mathsf{UltraFET}^{\mathbb{R}}$ SLIENT SWITCHER® FACT™ MICROWIRE™ FACT Quiet Series™ OPTOLOGIC™ SMART START™  $VCX^{TM}$ 

STAR\*POWER is used under license

#### **DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

### **PRODUCT STATUS DEFINITIONS**

### **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

©2001 Fairchild Semiconductor Corporation Rev. H3